



MMDT4146

COMPLEMENTARY NPN / PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Complementary Pair One 4124-Type NPN
 One 4126-Type PNP
- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

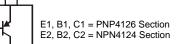
Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic, "Green" Molding Compound, Note 5. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating) Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering Information: See Page 4

Device Schematic

Weight: 0.006 grams (approximate)





Top View

Maximum Ratings, NPN 4124 Section @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	30	V
Collector-Emitter Voltage	V _{CEO}	25	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current – Continuous (Note 1)	lc	200	mA

Maximum Ratings, PNP 4126 Section @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-25	V
Emitter-Base Voltage	V _{EBO}	-4	V
Collector Current - Continuous (Note 1)	lc	-200	mA

Thermal Characteristics – Total Device

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 1, 2)	PD	200	mW
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ ext{ heta}JA}$	625	°C/W

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. Maximum combined dissipation.

3. No purposefully added lead.

4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics, NPN 4124 Section @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	30		V	$I_{C} = 10 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	25	_	V	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	5.0	_	V	$I_E = 10 \mu A, I_C = 0$
Collector Cutoff Current	I _{CBO}		50	nA	$V_{CB} = 20V, I_E = 0V$
Emitter Cutoff Current	I _{EBO}		50	nA	$V_{EB} = 3.0V, I_{C} = 0V$
ON CHARACTERISTICS (Note 6)					
DC Current Gain	h _{FE}	120	360 —	—	$I_{C} = 2.0 \text{mA}, V_{CE} = 1.0 \text{V}$
		60			$I_{C} = 50 \text{mA}, V_{CE} = 1.0 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		0.30	V	$I_{C} = 50 \text{mA}, I_{B} = 5.0 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}		0.95	V	$I_{\rm C} = 50 {\rm mA}, I_{\rm B} = 5.0 {\rm mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	Cobo		4.0	pF	$V_{CB} = 5.0V, f = 1.0MHz, I_E = 0$
Input Capacitance	Cibo	_	8.0	рF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$
Small Signal Current Gain	h _{fe}	120	480	_	V _{CE} = 1.0V, I _C = 2.0mA, f = 1.0kHz
Current Gain-Bandwidth Product	f _T	300	_	MHz	$V_{CE} = 20V, I_C = 10mA,$ f = 100MHz
Noise Figure	NF		5.0	dB	$V_{CE} = 5.0V, I_C = 100\mu A,$ $R_S = 1.0k\Omega, f = 1.0kHz$

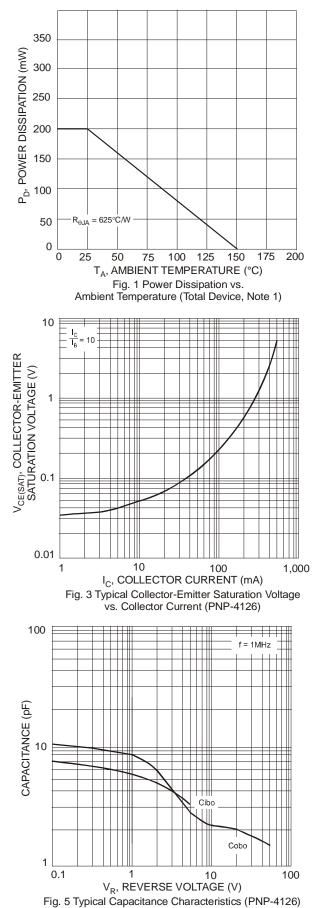
Electrical Characteristics, PNP 4126 Section @T_A = 25°C unless otherwise specified

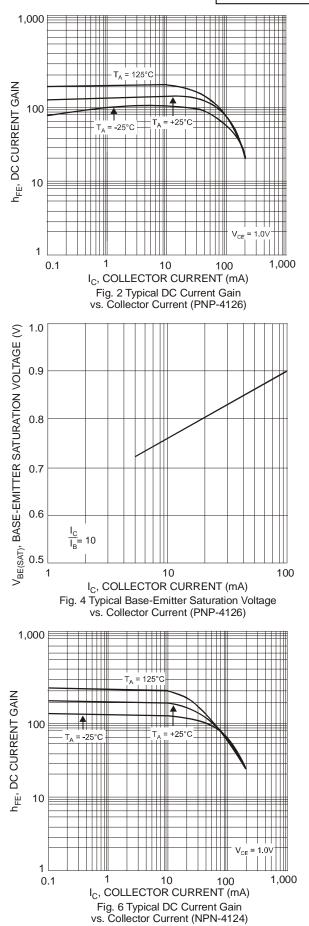
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-25	_	V	$I_{C} = -10\mu A$, $I_{E} = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-25	_	V	$I_{\rm C} = -1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-4.0	_	V	$I_{E} = -10\mu A, I_{C} = 0$
Collector Cutoff Current	I _{CBO}	_	-50	nA	$V_{CB} = -20V, I_E = 0V$
Emitter Cutoff Current	I _{EBO}	_	-50	nA	$V_{EB} = -3.0V, I_{C} = 0V$
ON CHARACTERISTICS (Note 6)					
DC Current Gain	h	120 60	360	—	$I_{C} = -2.0 \text{mA}, V_{CE} = -1.0 \text{V}$
	h _{FE}		_		$I_{C} = -50 \text{mA}, V_{CE} = -1.0 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.40	V	$I_{C} = -50 \text{mA}, I_{B} = -5.0 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	-0.95	V	$I_{C} = -50 \text{mA}, I_{B} = -5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	Cobo	_	4.5	pF	$V_{CB} = -5.0V, f = 1.0MHz, I_E = 0$
Input Capacitance	Cibo	_	10	pF	$V_{EB} = -0.5V, f = 1.0MHz, I_{C} = 0$
Small Signal Current Gain	h _{fe}	120	480	_	$V_{CE} = -1.0V, I_{C} = -2.0mA,$ f = 1.0kHz
Current Gain-Bandwidth Product	fT	250	— MHz V _{CE} = -20V, f = 100MHz		$V_{CE} = -20V, I_C = -10mA,$ f = 100MHz
Noise Figure	NF		4.0	dB	$V_{CE} = -5.0V, I_C = -100\mu A,$ $R_S = 1.0k\Omega, f = 1.0kHz$

Notes: 6. Short duration pulse test used to minimize self-heating effect.











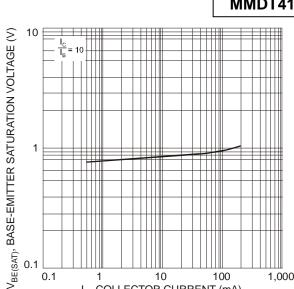
V_{CE(SAT)}, COLLECTOR-EMITTER SATURATION VOLTAGE (V) 0.1

0.01

0.1

1

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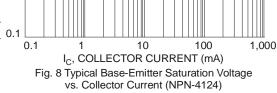


Fig. 7 Typical Collector-Emitter Saturation Voltage vs. Collector Current (NPN-4124) 15 f = 1MHz CAPACITANCE (pF) 10 5 Cibo Cobo 0 0.1 10 100 V_R, REVERSE VOLTAGE (V) Fig. 9 Typical Capacitance Characteristics (NPN-4124)

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I_C, COLLECTOR CURRENT (mA)

Ordering Information (Note 7)

Part Number	Case	Packaging
MMDT4146-7-F	SOT-363	3000/Tape & Reel

1,000

100

7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf. Notes:

Marking Information

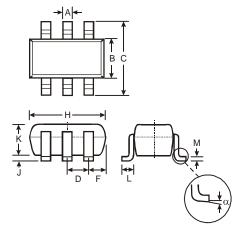
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►	(12	ΥM	K12 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: N = 2002) M = Month (ex: 9 = September)
			M = Month (ex: 9 = September)

Date Code Ke	у																	
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015
Code	J	K	L	М	Ν	Р	R	S	Т	U	V	W	Х	Y	Z	Α	В	С
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Month	Jan		Feb	Ma	r	Apr	May	/	Jun	Ju		Aug	Sep		Oct	Nov	1	Dec
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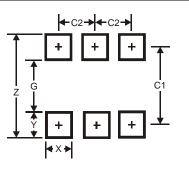


Package Outline Dimensions



	SOT-363						
Dim	Dim Min Max						
Α	0.10	0.30					
В	B 1.15 1.35						
С	C 2.00 2.20						
D	0.65 Typ						
F	F 0.40 0.45						
Н	H 1.80 2.20						
J	J 0 0.10						
κ	K 0.90 1.00						
L	0.25	0.40					
М	M 0.10 0.22						
α	0°	8°					
All Di	mensions	in mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
C1	1.9
C2	0.65

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